

IFN401, IFN402, IFN403, IFN404, IFN405, IFN406

N-Channel Matched Dual Silicon Junction Field-Effect Transistor

- Improved Replacements for the U401, U402, U403, U404, U405, U406
- Low Noise Differential Amplifier
- Wide-Band Amplifier
- Precision Instrumentation Amplifier

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

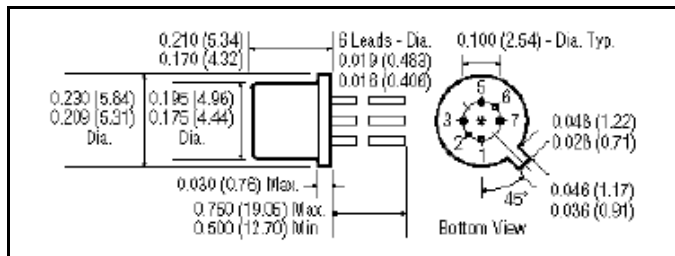
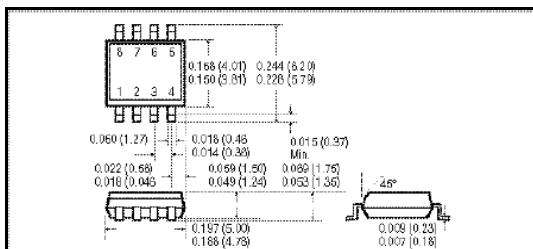
Reverse Gate Source & Gate Drain Voltage	-50V
Continuous Forward Gate Current	10 mA
Continuous Device Power Dissipation	300 mW
Power Derating	4.3 mW/ $^\circ\text{C}$
Operating Temperature Range	-55 $^\circ\text{C}$ to +125 $^\circ\text{C}$
Storage Temperature Range	-65 $^\circ\text{C}$ to +150 $^\circ\text{C}$

At 25 $^\circ\text{C}$ free air temperature		401, 402, 403, 404, 405, 406				Process NJ16	
Static Electrical Characteristics		Min	Typ	Max	Unit	Test Conditions	
Gate Source Breakdown Voltage	$V_{(BR)GSS}$	-50			V	$I_G = -1 \text{ uA}$, $V_{DS} = 0 \text{ V}$	
Gate Reverse Current	I_{GSS}			-25	pA	$V_{GS} = -30 \text{ V}$, $V_{DS} = 0 \text{ V}$	
Gate Source Cutoff Voltage	$V_{GS(OFF)}$	-0.5		-2.5	V	$V_{DS} = 15 \text{ V}$, $I_D = 1 \text{ nA}$	
Gate Source On Voltage	$V_{GS(ON)}$			-2.3	V	$V_{DG} = 15 \text{ V}$, $I_D = 200 \text{ uA}$	
Drain Saturation Current (pulsed)	I_{DSS}	0.5		10	mA	$V_{DS} = 10 \text{ V}$, $V_{GS} = 0 \text{ V}$	
Gate Current	I_G			-50 -10	pA nA	$V_{DG} = 10 \text{ V}$, $I_D = 200 \text{ uA}$	125 $^\circ\text{C}$

Dynamic Electrical Characteristics

Common-Source Forward Transconductance	g_{fs}	0.5		2	mS	$V_{DS} = 15 \text{ V}$, $I_D = 400 \text{ uA}$	$f = 1 \text{ kHz}$
Common-Source Output Transconductance	g_{os}			2	uS	$V_{DS} = 15 \text{ V}$, $I_D = 200 \text{ uA}$	$f = 1 \text{ kHz}$
Common-Source Input Capacitance	C_{iss}			8	pF	$V_{DS} = 15 \text{ V}$, $I_D = 200 \text{ uA}$	$f = 1 \text{ MHz}$
Common-Source Reverse Transfer Capacitance	C_{rss}			3	pF	$V_{DS} = 15 \text{ V}$, $I_D = 200 \text{ uA}$	$f = 1 \text{ MHz}$
Equivalent Short Circuit Input Noise Voltage	$\sim e_N$			20	nV/ $\sqrt{\text{Hz}}$	$V_{DS} = 15 \text{ V}$, $V_{GS} = 0 \text{ V}$	$f = 10 \text{ Hz}$

Matching Characteristics (Max)		401	402	403	404	405	406	Units	Test Conditions
Differential Gate-Source Voltage	$ V_{GS1} - V_{GS2} $	5	10	10	15	20	40	mV	$V_{DG} = 10 \text{ V}$, $I_D = 200 \text{ uA}$
Differential Gate Source Voltage w/ Temperature (-55 $^\circ\text{C}$, 25 $^\circ\text{C}$, 125 $^\circ\text{C}$)	$\Delta V_{GS1} - V_{GS2} / \Delta T$	10	10	25	25	40	80	$\mu\text{V}/^\circ\text{C}$	$V_{DG} = 10 \text{ V}$, $I_D = 200 \text{ uA}$



SOIC-8 Package Pin Configuration
 SMPU401, SMPU402, 1-G1, 2-D1, 3-S1, 4-G2,
 SMPU403, SMPU404 5-G2, 6-D2, 7-S2, 8-G1
 SMPU405, SMPU406

TO-71: Pin Configuration
 IFN401, IFN 402, IFN 403,, 1-S1, 2-D1, 3-G1,
 IFN 404, IFN 405, IFN 406 4-S2, 5-D2, 6-G2
 Dimensions in Inches (mm)



715 N. Glenville Dr., Ste. 400
 Richardson, TX 75081
 (972) 238-9700 Fax (972) 238-5338
www.interfet.com

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com